

Super Barrier Rectifier™

Using state-of-the-art SBR IC process technology,
the following features are made possible in a single device:

Major ratings and characteristics

Characteristics	Values	Units
$I_{F(AV)}$ Rectangular Waveform	20	A
V_{RRM}	100	V
$V_F @ 10A, T_j = 125^\circ C$	0.67	V, typ
T_j (operating/storage)	-65 to 175	$^\circ C$





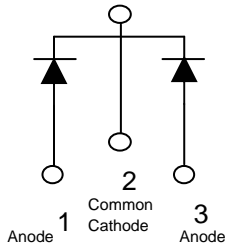
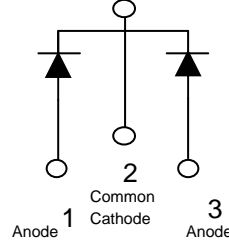
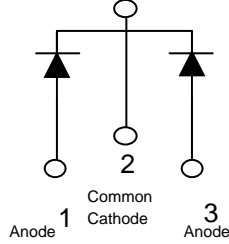
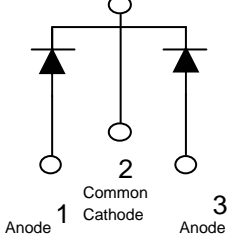
**Device optimized for high temperature
Power Supply applications**

ELECTRICAL:

- * Low Forward Voltage Drop
- * Reliable High Temperature Operation
- * Super Barrier Design
- * Softest, Fast Switching Capability
- * 175 $^\circ C$ Operating Junction Temperature

MECHANICAL:

- * Molded Plastic TO-220AB, TO-262, TO-263, and ITO-220 packages

Case Styles			
SBR20100CT	SBR20100CTF	SBR20100CTI	SBR20100CTB
			
			
TO-220AB	ITO-220	TO-262	TO-263

Maximum Ratings and Electrical Characteristics (at 25°C unless otherwise specified)				
	SYMBOL			UNITS
DC Blocking Voltage Working Peak Reverse Voltage Peak Repetitive Reverse Voltage	V_{RM} V_{RWM} V_{RRM}	100		Volts
Average Rectified Forward Current (Rated V_R -20Khz Square Wave) - 50% duty cycle	I_O	20		Amps
Peak Forward Surge Current - 1/2 60hz	I_{FSM}	120		Amps
Peak Repetitive Reverse Surge Current (2uS-1Khz)	I_{RRM}	2		Amps
Instantaneous Forward Voltage (per leg) $I_F = 10A; T_J = 25^\circ C$ $I_F = 10A; T_J = 125^\circ C$	V_F	Typ --- ---	Max 0.82 0.75	Volts
Maximum Instantaneous Reverse Current at Rated V_{RM} $T_J = 25^\circ C$ $T_J = 125^\circ C$	I_R^*	Typ --- ---	Max 100 10	uA mA
Maximum Rate of Voltage Change (at Rated V_R)	dv/dt	10,000		V/uS
Maximum Thermal Resistance JC (per leg) Package = TO-220AB, TO-262, & TO-263 Package = ITO-220	$R_{\theta_{JC}}$	2 4		°C/W
Operating and Storage Junction Temperature	T_J	-65 to +175		°C

* Pulse width < 300 uS, Duty cycle < 2%

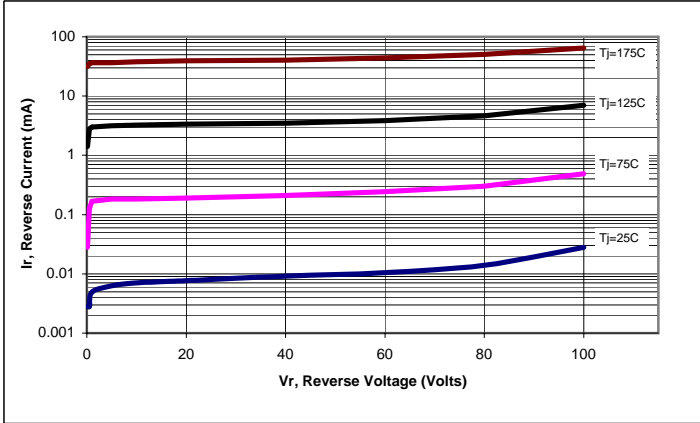


Figure 1: Typical Reverse Current

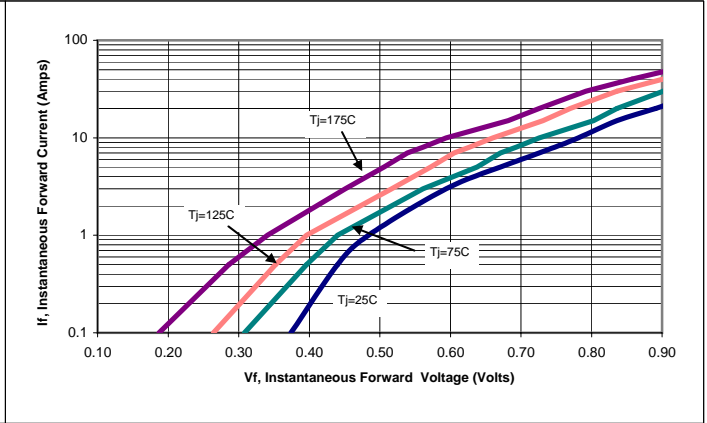


Figure 2: Typical Forward Voltage

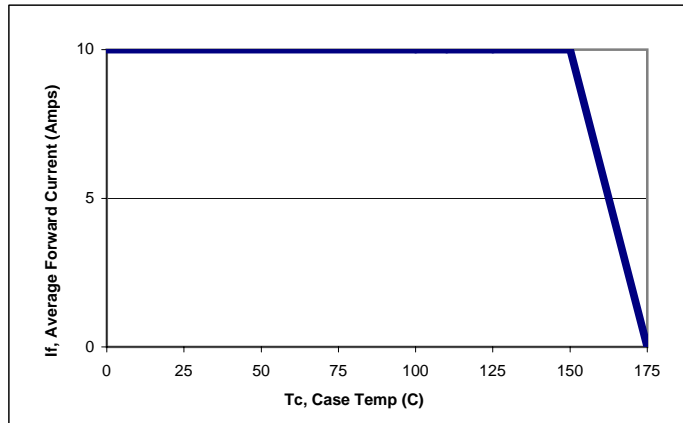


Figure 3: Current Derating, Case

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